PNP/NPN Epitaxial Planar Silicon Transistors



2SA1415/2SC3645

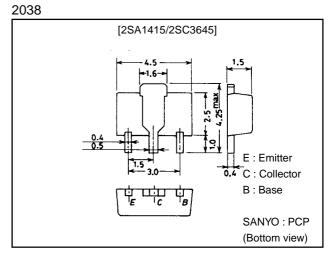
High-Voltage Switching, **Predriver Applications**

Features

- · Adoption of FBET process.
- · High breakdown voltage (V_{CEO} =160V).
- \cdot Excellent linearity of h_{FE} and small Cob.
- · Fast switching speed.
- · Very small size marking it easy to provide highdensity, small-sized hybrid ICs.

Package Dimensions

unit:mm



(): 2SA1415

Specifications

Absolute Maximum Ratings at Ta = 25°C

Parameter	Symbol	Conditions	Ratings	Unit
Collector-to-Base Voltage	VCBO		(–)180	V
Collector-to-Emitter Voltage	VCEO		(–)160	V
Emitter-to-Base Voltage	V _{EBO}		(–)5	V
Collector Current	ι _C		(–)140	mA
Collector Current (Pulse)	I _{CP}		(-)200	mA
Collector Dissipation	P _C 1		500	mW
	P _C 2	Moutned on ceramic board (250mm ² ×0.8mm)	1.3	W
Junction Temperature	Tj		150	°C
Storage Temperature	Tstg		-55 to +150	°C

Electrical Characteristics at Ta = 25°C

Symbol	Conditions	Ratings			Unit
		min	typ	max	Unit
ICBO	V _{CB} =(-)80V, I _E =0			(–)100	nA
IEBO	V _{EB} =(-)4V, I _C =0			(–)100	nA
hFE	V _{CE} =(-)5V, I _C =(-)10mA	100*		400*	
fT	V _{CE} =(-)10V, I _C =(-)10mA		150		MHz
Cob	V _{CB} =(-)10V, f=1MHz		(4.0)		pF
			3.0		pF
V _{CE(sat)}	I _C =(-)50mA, I _B =(-)5mA		(-0.14)	(-0.4)	V
			0.07	0.3	V
ton	See sepcified Test Circuit.		0.1		μs
^t stg	See sepcified Test Circuit.		1.5		μs
t _f	See sepcified Test Circuit.		0.1		μs
	ICBO IEBO hFE fT Cob VCE(sat) ton tstg	$\begin{tabular}{ c c c c c c c c c c c c c c c c c c c$	Imin min ICBO VCB=(-)80V, IE=0 Imin IEBO VEB=(-)4V, IC=0 Imin hFE VCE=(-)5V, IC=(-)10mA 100* fT VCE=(-)10V, IC=(-)10mA Imin Cob VCB=(-)10V, IC=(-)10mA Imin VCB VCB=(-)10V, IC=(-)10mA Imin VCE(sat) IC=(-)50mA, IB=(-)5mA Imin ton See sepcified Test Circuit. Imin tstg See sepcified Test Circuit. Imin	$\begin{tabular}{ c c c c c } \hline Symbol & Conditions & \hline min & typ \\ \hline I_{CBO} & V_{CB}=(-)80V, I_E=0 & & & & \\ \hline I_{EBO} & V_{EB}=(-)4V, I_C=0 & & & & \\ \hline I_{EBO} & V_{CB}=(-)5V, I_C=(-)10mA & 100^* & & \\ \hline f_T & V_{CE}=(-)10V, I_C=(-)10mA & & & 150 & \\ \hline C_{Ob} & V_{CB}=(-)10V, f=1MHz & & & & (4.0) & & \\ \hline & & & & & & & \\ \hline C_{C}(sat) & I_{C}=(-)50mA, I_{B}=(-)5mA & & & & & & \\ \hline V_{CE}(sat) & I_{C}=(-)50mA, I_{B}=(-)5mA & & & & & & & \\ \hline & & & & & & & & & \\ \hline V_{CE}(sat) & I_{C}=(-)50mA, I_{B}=(-)5mA & & & & & & & \\ \hline & & & & & & & & & \\ \hline & & & &$	$\begin{tabular}{ c c c c c } \hline & C & C & \hline & min & typ & max \\ \hline min & tstg & see sepcified Test Circuit. \\ \hline min & tstg & see sepcified Test Circuit. \\ \hline min & tstg & term & typ & max \\ \hline min & tstg & term & term & typ & max \\ \hline min & tstg & term & ter$

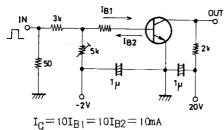
 \ast : The 2SA1415/2SC3645 are classified by 10mA h_{FE} as follows :

100 R 200 140 S 280 200 T 400 Marking 2SA1415 : AA h_{FE} rank : R, S, T

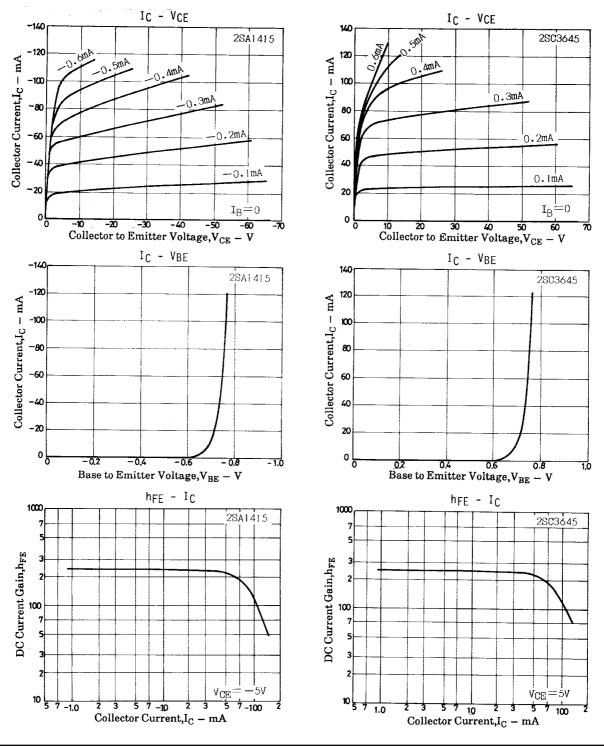
2SC3645 : CA

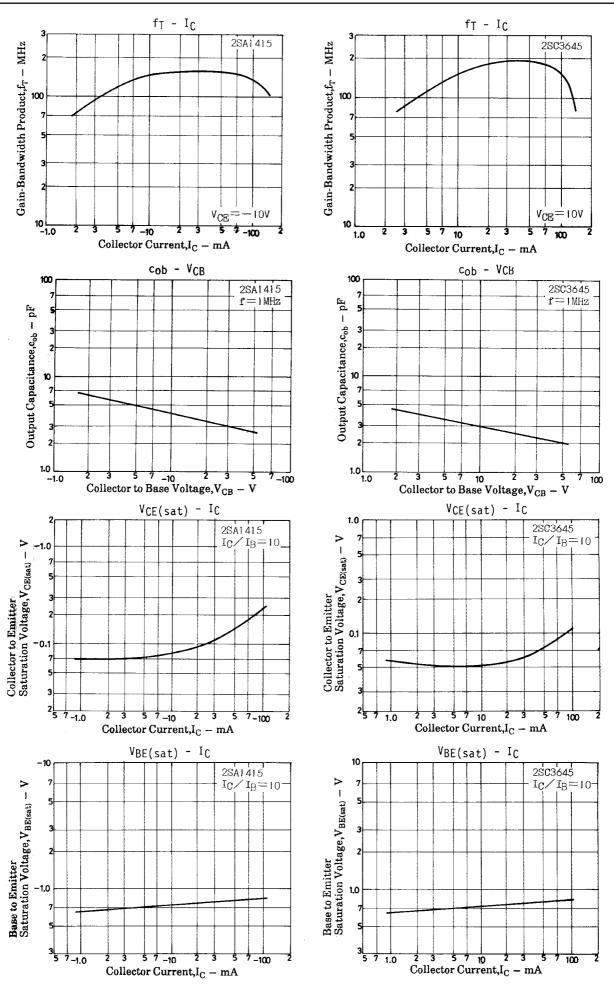
SANYO Electric Co., Ltd. Semiconductor Bussiness Headquaters TOKYO OFFICE Tokyo Bldg., 1-10, 1 Chome, Ueno, Taito-ku, TOKYO, 110-8534 JAPAN

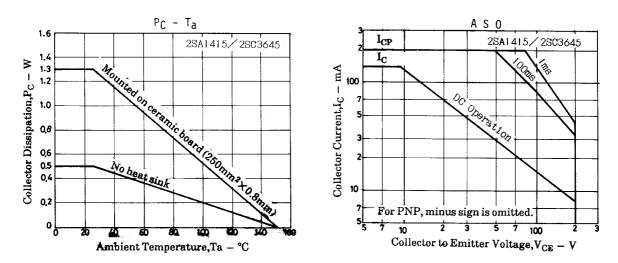
Switching Time Test Circuit



(For PNP, the polarity is reversed) Unit (resistance : Ω , capacitance : F)







■ No products described or contained herein are intended for use in surgical implants, life-support systems, aerospace equipment, nuclear power control systems, vehicles, disaster/crime-prevention equipment and the like, the failure of which may directly or indirectly cause injury, death or property loss.

Anyone purchasing any products described or contained herein for an above-mentioned use shall:

- ① Accept full responsibility and indemnify and defend SANYO ELECTRIC CO., LTD., its affiliates, subsidiaries and distributors and all their officers and employees, jointly and severally, against any and all claims and litigation and all damages, cost and expenses associated with such use:
- ② Not impose any responsibility for any fault or negligence which may be cited in any such claim or litigation on SANYO ELECTRIC CO., LTD., its affiliates, subsidiaries and distributors or any of their officers and employees jointly or severally.
- Information (including circuit diagrams and circuit parameters) herein is for example only; it is not guaranteed for volume production. SANYO believes information herein is accurate and reliable, but no guarantees are made or implied regarding its use or any infringements of intellectual property rights or other rights of third parties.

This catalog provides information as of July, 1998. Specifications and information herein are subject to change without notice.